	Specification	Symbol	Condition / Comment		201-180 SiC	201-240 SiC	201-300 SiC	Unit
ABSOLUTE MAXIMUM RATINGS	Maximum Operating Voltage	$V_{O(max)}$	I_{off} < 80 µADC, T_{case} = 70°C			20		kVDC
	Maximum Isolation Voltage	V_I	Between HV switch and control / GND, continuously			± 30		kVDC
	Max. Housing Insulation Voltage	V_{INS}	Between switch and housing surface, 3 minutes			± 50		kVDC
	Maximum Turn-On Peak Current	$I_{P(max)}$	T_{case} = 25°C	t_p< 200 µs, duty cycle <1%	1800	2400	3000	
				t_p< 1 ms, duty cycle <1%	1000	1400	1900	
				t_p< 10 ms, duty cycle <1%	340	500	500	
				t_p< 100 ms, duty cycle <1%	120	240	300	ADC
	Maximum Continuous Load Current	$I_{L(max)}$	T_{case} = 25°C	Standard devices	7	10	38	
				Devices with option DLC	50	80	100	ADC
	Max. Continuous Power Dissipation	$P_{d(max)}$	T_{case} = 25°C	Standard devices & FC, forced air 4 m/s	100	140	210	
				Devices with option DLC	1500	2000	3000	Watt
	Linear Derating		Above 25°C	Standard devices & FC, forced air 4 m/s	0.3	0.4	0.7	
				Devices with option DLC	133	186	240	W/K
	Operating Temperature Range	T_O	Standard devices & options CF, GCF, ILC. (Option DLC)			-40...70 (60)		°C
	Storage Temperature Range	T_S	Switches with option ILC may require frost protection!			-40...90		°C
	Max. Permissible Magnetic Field	B	Homogeneous steady-field, surrounding the whole switch			25		mT
	Max. Auxilliary Voltage	V_{aux}	Built-in overvoltage limiter (replaceable)			5.5		VDC
ELECTRICAL CHARACTERISTICS	Permissible Operating Voltage Range	V_O				0... ± 20		kVDC
	Typical Breakdown Voltage	V_{br}	**NOTE:** V_{br} is a test parameter for quality control purposes only. Not applicable in normal operation!	I_{off} > 0.5 mA		22		kVDC
	Typical Off-State Current	I_{off}	0.8xV_O, T_{case} =25...70°C, reduced I_{off} on request			< 80		µADC
	Typical Turn-On Resistance	R_{stat}	Each switching path, t_p < 1µs, duty cycle < 1%	0.1 x $I_{P(max)}$, T_{case} =25°C	0.067	0.05	0.04	
				1.0 x $I_{P(max)}$, T_{case} =25°C	0.1	0.075	0.0172	
				1.0 x $I_{P(max)}$, T_{case} =70°C	0.2	0.15	0.144	Ohm
	Typical Propagation Delay Time	$t_{d(on)}$	Resistive load, 0.1 x $I_{P(max)}$, 0.8 x $V_{O(max)}$, 50-50%			200		ns
	Typical Output Pulse Jitter	t_j	Impedance matched input, V_{aux} / V_{ctrl} = 5.00 VDC			3		ns
	Typical Turn-On Rise Time	$t_{r(on)}$	Resistive load, 10-90%	0.1 x $V_{O(max)}$, I_L = 0.1 x $I_{p(max)}$		30		
				0.8 x $V_{O(max)}$, I_L = 0.1 x $I_{p(max)}$		45		
				0.8 x $V_{O(max)}$, I_L = 1.0 x $I_{p(max)}$		60		ns
	Typical Turn-Off Rise Time	t_{off}, t_q	Resistive load, 10-90%	0.1 x $V_{O(max)}$, I_L = 0.1 x $I_{p(max)}$		50		
				0.8 x $V_{O(max)}$, I_L = 1.0 x $I_{p(max)}$		100		ns
	Maximum Turn-On Time	$t_{on(max)}$	No limitation			∞		ns
	Minimum Turn-On Time	$t_{on(min)}$	$t_{on(min)}$ can be customized. Please consult factory			150		ns
	Maximum Turn-Off Time	$t_{off(max)}$	No limitation			∞		ns
	Minimum Turn-Off Time	$t_{off(min)}$	$t_{off(min)}$ can be customized. Please consult factory			150		ns
	Max. Continuous Switching Frequency	$f_{(max)}$	@ V_{aux}= 5.00 V, Sw. shutdown if $f_{(max)}$ is exceeded	Standard devices without HFS option		TBD		
				Standard devices with HFS supply		30		
				Opt. HFS + sufficient cooling option		80		kHz
	Maximum Burst Frequency	$f_{b(max)}$	Use option HFB for >10 pulses within 20µs or less			500		kHz
	Maximum Number of Pulses / Burst	$N_{(max)}$	@ $f_{b(max)}$ Note: Option HFB requires external buffer capacitors with a voltage rating of > 630VDC and a cpacitance of 100nF per additional pulse.	Standard		>10		
				Option I-HFB		>100		
				Option HFB		>1000		Pulses
	Coupling Capacitance	C_C	HV side against control side			<100		pF
	Natural Capacitance	C_N	Between switch poles, @ 0.5 x $V_{O(max)}$		9	8	6	pF
	Control Voltage Range	V_{ctrl}	The V_{ctrl} has no impact on the output pulse shape.			3 ... 10		VDC
	Auxiliary Supply Voltage Range	V_{aux}	The +5 V supply is not required in the HFS mode.			4.5 ... 5.5		VDC
	Typical Auxiliary Supply Current	I_{aux}	V_{aux} = 5.00 VDC, T_{case} = 25°C.	0.01 x $f_{(max)}$		220		
			Active current limitation above 1A.	@ $f_{(max)}$		600		mADC
	Fault Signal Output		Switch will be turn off, if f>$f_{(max)}$, V_{aux}<4.75V or T_{case}>75°C			>4.0		
			Fault condition is indicated by a logical "L"			<0.8		VDC
	Opt. HFS, Ext. Supply Voltage V1	$V_{HFS(V1)}$	Stability ±3%, current consumption <0.4 mA/kHz @ 25°C			15		VDC
	Opt. HFS, Ext. Supply Voltage V2	$V_{HFS(V2)}$	Stability ±3%, current consumption <0.5 mA/kHz @ 25°C			TBD		VDC
	Intrinsic Diode Forward Voltage	V_F	T_{case} = 25°C, I_F = 0.3 x $I_{P(max)}$			<30		VDC
	Diode Reverse Recovery Time	t_{rrc}	T_{case} = 25°C, I_F = 0.3 x $I_{P(max)}$, di/dt = 100 A/µs			<50		ns
HOUSING	Dimensions	LxWxH	Standard housing Devices with option DLC			Please contact the manufactured!		mm^3
	Weight		Standard housing Devices with option DLC			Please contact the manufactured!		g

FUNCTIONS	
Control Signal Input	**Pin 1** / Yellow (LS-C: Pin 1). TTL compatible (LS-C: With 100Ω termination). Schmitt-Trigger characteristics. Control voltage 2-10 V (3-5 V for low jitter).
Logic GND / 5V Return	**Pin 2** / Black (LS-C: Shielding). The ground pin is internally connected with the safety earthings terminals (threaded inserts) on bottom side.
5V Auxiliary Supply	**Pin 3** / Red (LS-C: Pin 4). The 5 V input is used for rep rates up to the specified max. frequency $f_{(max)}$. Higher rep rates require option HFS.
Fault Signal Output	**Pin 4** / Orange (LS-C: Pin 3). TTL output, short circuit proof. Indicating switch & driver over-heat, over-frequency, low auxiliary voltage. L = Fault.
Inhibit Signal Input	**Pin 5** / Green (LS-C: Pin 2). TTL compatible, Schmitt-Trigger characteristics for the connection of external safety circuits. L = Switch Inhibited.
LED Indicators	**GREEN**: "Auxiliary power good, switch OFF". **YELLOW**: "Control signal received, switch ON". **RED**: "Fault condition, switch OFF"
Temperature Protection	Switches with option DLC: 65°C, response time < 3 s @ 3xPd(max), ΔT=25K (40 to 65°C), coolant flow > 3l / min. Separate driver protection.

ORDERING

HTS 201-180 SiC	Fast HV SiC Mosfet Switch, 20kV, 1800 A	**Option LP**	Low Pass. Input filter for increased noise immunity.	**Option I-PC**	Integrated part components according to customer specification.
HTS 201-240 SiC	Fast HV SiC Mosfet Switch, 20kV, 2400 A	**Option HFB**	High Frequency Burst (improved capability by external capacitors)	**Option UL-94**	Flame retardant casting resin, UL94-V0
HTS 201-300 SiC	Fast HV SiC Mosfet Switch, 20kV, 3000 A	**Option HFS**	High Frequency Switching (two auxiliary supply inputs V1 & V2)	**Option I-FWD**	Integrated Free-Wheeling Diode. In connection with inductive load only.
		Option I-HFS	Integrated High Frequency Burst	**Option I-FWDN**	Integrated Freewheeling Diode Network. In connection with inductive load.
		Option S-TT	Soft Transition Time decrease the rise and fall time by 20%	**Option PT-C**	Pigtail for control connection: Flexible leads (l=75mm) with lemo
		Option Min-On	Individually increased "Min. On-Time" to avoid unwanted triggering	**Option SEP-C**	Separated control unit. Control unit with LED indicators in a separate
		Option Min-Off	Individually increased "Min. Off-Time" to avoid unwanted triggering	**Option TH**	Tubular Housing
		Option PCC	Pulser Configuration. Switch combined with custom specific parts.	**Option CF**	Copper Cooling Fins. $P_{d(max)}$ can be increased by the factor 3 to 10.
		Option ISO-40	40kV Isolation. Isolation Voltage increased to 120kV.	**Option DLC**	Direct Liquid Cooling. $P_{d(max)}$ can be increased by the factor 10 to 100.
		Option ISO-60	60kV Isolation. Isolation Voltage increased to 200kV.	**FOR FURTHER PRODUCT OPTIONS PLEASE REFER TO THE OPTIONS PAGE.**	